



OPA2241 OPA2241 OPA4241 OPA251 OPA2251 OPA2251

# Single-Supply, *Micro*POWER OPERATIONAL AMPLIFIERS

**OPA241 Family** optimized for +5V supply. **OPA251 Family** optimized for ±15V supply.

## FEATURES

- *Micro*POWER:  $I_Q = 25\mu A$
- SINGLE-SUPPLY OPERATION
- RAIL-TO-RAIL OUTPUT (within 50mV)
- WIDE SUPPLY RANGE Single Supply: +2.7V to +36V Dual Supply: ±1.35V to ±18V
- LOW OFFSET VOLTAGE: ±250µV max
- HIGH COMMON-MODE REJECTION: 124dB
- HIGH OPEN-LOOP GAIN: 128dB
- SINGLE, DUAL, AND QUAD

# **APPLICATIONS**

- BATTERY OPERATED INSTRUMENTS
- PORTABLE DEVICES
- MEDICAL INSTRUMENTS
- TEST EQUIPMENT

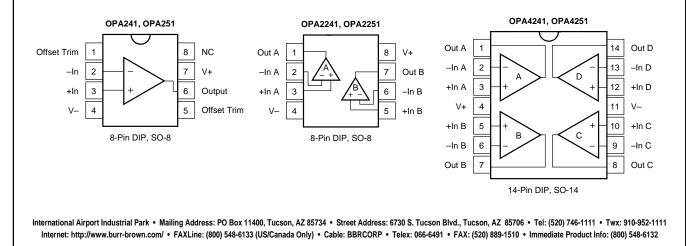
# DESCRIPTION

The OPA241 series and OPA251 series are specifically designed for battery powered, portable applications. In addition to very low power consumption (25 $\mu$ A), these amplifiers feature low offset voltage, rail-to-rail output swing, high common-mode rejection, and high open-loop gain.

The OPA241 series is optimized for operation at low power supply voltage while the OPA251 series is optimized for high power supplies. Both can operate from either single (+2.7V to +36V) or dual supplies ( $\pm 1.35V$  to  $\pm 18V$ ). The input common-mode voltage range extends 200mV below the negative supply—ideal for single-supply applications.

They are unity-gain stable and can drive large capacitive loads. Special design considerations assure that these products are easy to use. High performance is maintained as the amplifiers swing to their specified limits. Because the initial offset voltage ( $\pm 250\mu V$  max) is so low, user adjustment is usually not required. However, external trim pins are provided for special applications (single versions only).

The OPA241 and OPA251 (single versions) are available in standard 8-pin DIP and SO-8 surface-mount packages. The OPA2241 and OPA2251 (dual versions) come in 8-pin DIP and SO-8 surface-mount packages. The OPA4241 and OPA4251 (quad versions) are available in 14-pin DIP and SO-14 surface-mount packages. All are fully specified from  $-40^{\circ}$ C to  $+85^{\circ}$ C and operate from  $-55^{\circ}$ C to  $+125^{\circ}$ C.



# SPECIFICATIONS: $V_s = 2.7V$ to 5V

At T<sub>A</sub> = +25°C, R<sub>L</sub> = 100k $\Omega$  connected to V<sub>S</sub>/2, unless otherwise noted. **Boldface** limits apply over the specified temperature range,  $T_A = -40^{\circ}C$  to  $+85^{\circ}C$ .

			OPA	OPA241UA, PA         OPA251UA, PA           OPA2241UA, PA         OPA2251UA, PA           OPA4241UA, PA         OPA4251UA, PA					
PARAMETER		CONDITION	MIN	TYP <sup>(1)</sup>	МАХ	MIN	TYP <sup>(1)</sup>	МАХ	UNITS
OFFSET VOLTAGEInput Offset Voltage $T_A = -40^{\circ}C$ to +85°Cvs Temperaturevs Power Supply $T_A = -40^{\circ}C$ to +85°CChannel Separation (dual, quad)	V <sub>OS</sub> dV <sub>OS</sub> /dT PSRR	$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $V_{S} = 2.7V \text{ to } 36V$ $V_{S} = 2.7V \text{ to } 36V$		±50 ± <b>100</b> ± <b>0.4</b> 3 0.3	±250 ± <b>400</b> 30 <b>30</b> <b>30</b>		±100 ±130 ±0.6 *	* *	μV μV μV/°C μV/∨ μV/∨ μV/∨
INPUT BIAS CURRENT Input Bias Current <sup>(2)</sup> $T_A = -40^{\circ}$ C to +85°C Input Offset Current $T_A = -40^{\circ}$ C to +85°C	I <sub>B</sub> I <sub>OS</sub>			-4 ±0.1	-20 - <b>25</b> ±2 ±2		*		nA nA nA nA
NOISE Input Voltage Noise, f = 0.1Hz to 1 Input Voltage Noise Density, f = 1k Current Noise Density, f = 1kHz				1 45 40			* * *		µVp-p nV/√Hz fA/√Hz
INPUT VOLTAGE RANGE Common-Mode Voltage Range Common-Mode Rejection Ratio $T_A = -40^{\circ}$ C to +85°C	V <sub>CM</sub> CMRR	$V_{CM} = -0.2V$ to (V+) -0.8V $V_{CM} = 0V$ to (V+) -0.8V	-0.2 80 <b>80</b>	106	(V+) -0.8		*		V dB dB
INPUT IMPEDANCE Differential Common-Mode				10 <sup>7</sup>    2 10 <sup>9</sup>    4			*		Ω    pF Ω    pF
OPEN-LOOP GAIN Open-Loop Voltage Gain $T_A = -40^{\circ}C$ to +85°C $T_A = -40^{\circ}C$ to +85°C	A <sub>OL</sub>	$\begin{array}{l} R_L = 100 k\Omega, \ V_O = (V-) + 100 mV \ to \ (V+) - 100 mV \\ R_L = 100 k\Omega, \ V_O = (V-) + 100 mV \ to \ (V+) - 100 mV \\ R_L = 10 k\Omega, \ V_O = (V-) + 200 mV \ to \ (V+) - 200 mV \\ R_I = 10 k\Omega, \ V_O = (V-) + 200 mV \ to \ (V+) - 200 mV \end{array}$	100 <b>100</b> 100 <b>100</b>	120 120			*		dB dB dB dB
FREQUENCY RESPONSE Gain-Bandwidth Product Slew Rate Overload Recovery Time	GBW SR	$V_{S} = 5V, G = 1$ $V_{IN} \bullet G = V_{S}$	100	35 0.01 60			* * *		kHz V/μs μs
OUTPUT Voltage Output Swing from Rail <sup>(3)</sup> $T_A = -40^{\circ}C$ to $+85^{\circ}C$	Vo	$\begin{array}{l} R_L = 100 k\Omega \text{ to } V_S/2, \ A_{OL} \geq 70 dB \\ R_L = 100 k\Omega \text{ to } V_S/2, \ A_{OL} \geq 100 dB \\ R_L = 100 k\Omega \text{ to } V_S/2, \ A_{OL} \geq 100 dB \\ R_L = 10 k\Omega \text{ to } V_S/2, \ A_{OL} \geq 100 dB \end{array}$		50 75 100	100 <b>100</b> 200		* *		mV mV mV mV
$T_A = -40^{\circ}C$ to +85°C Short-Circuit Current Single Versions Dual, Quad Versions Capacitive Load Drive	I <sub>SC</sub> C <sub>LOAD</sub>	$R_L = 10k\Omega$ to $V_S/2$ , $A_{OL} \ge 100dB$		-24/+4 -30/+4 Typical C	200		* *		mV mA mA
POWER SUPPLYSpecified Voltage RangeOperating Voltage RangeQuiescent Current (per amplifier) $T_A = -40^{\circ}$ C to +85°C	V <sub>s</sub> I <sub>Q</sub>	$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $I_{O} = 0$ $I_{O} = 0$	+2.7	+2.7 to +5 ±25		*	*	*	ν ν μΑ μΑ
TEMPERATURE RANGE Specified Range Operating Range Storage Range Thermal Resistance 8-Pin DIP SO-8 Surface Mount	$ heta_{JA}$		-40 -55 -55	100 150	+85 +125 +125	* *	*	* * *	°C °C °C °C/W °C/W
14-Pin DIP SO-14 Surface Mount				80 100			* *		°C/W °C/W

\* Specifications the same as OPA241UA, PA.

NOTES: (1) V<sub>S</sub> = +5V. (2) The negative sign indicates input bias current flows out of the input terminals. (3) Output voltage swings are measured between the output and power supply rails.

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# SPECIFICATIONS: $V_S = \pm 15V$

At  $T_A = +25^{\circ}C$ ,  $R_L = 100k\Omega$  connected to ground, unless otherwise noted. Boldface limits apply over the specified temperature range,  $T_A = -40^{\circ}C$  to +85°C.

			OP	A241UA, F A2241UA, A4241UA,	PA	OP OP/ OP/			
PARAMETER		CONDITION	MIN	ТҮР	МАХ	MIN	ТҮР	МАХ	UNITS
OFFSET VOLTAGEInput Offset Voltage $T_A = -40^{\circ}C$ to $+85^{\circ}C$ vs Temperaturevs Power Supply $T_A = -40^{\circ}C$ to $+85^{\circ}C$ Channel Separation (dual, quad)	V <sub>OS</sub> dV <sub>OS</sub> /dT PSRR	<b>T<sub>A</sub> = -40°C to +85°C</b> V <sub>S</sub> = ±1.35V to ±18V V <sub>S</sub> = ±1.35V to ±18V		±100 ±150 ±0.6 *	* *		$\pm 50 \\ \pm 100 \\ \pm 0.5 \\ 3 \\ 0.3$	±250 ± <b>300</b> 30 <b>30</b> <b>30</b>	μV μV μV/°C μV/V μV/V μV/V
INPUT BIAS CURRENT Input Bias Current <sup>(1)</sup> $T_A = -40^{\circ}$ C to +85°C Input Offset Current $T_A = -40^{\circ}$ C to +85°C	I <sub>B</sub> I <sub>OS</sub>			*			-4 ±0.1	-20 -25 ±2 ±2	nA nA nA nA
NOISE Input Voltage Noise, f = 0.1Hz to 1 Input Voltage Noise Density, f = 1k Current Noise Density, f = 1kHz				* * *			1 45 40		μVp-p nV/√Hz fA/√Hz
INPUT VOLTAGE RANGE Common-Mode Voltage Range Common-Mode Rejection Ratio $T_A = -40^{\circ}$ C to +85°C	V <sub>CM</sub> CMRR	$V_{CM} = -15.2V$ to 14.2V $V_{CM} = -15V$ to 14.2V		*		(V–) –0.2 100 <b>100</b>	124	(V+) -0.8	V dB dB
INPUT IMPEDANCE Differential Common-Mode				*			10 <sup>7</sup>    2 10 <sup>9</sup>    4		Ω    pF Ω    pF
OPEN-LOOP GAIN Open-Loop Voltage Gain $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	A <sub>OL</sub>			*		100 <b>100</b> 100 <b>100</b>	128 128		dB dB dB dB
FREQUENCY RESPONSE Gain-Bandwidth Product Slew Rate Overload Recovery Time	GBW SR	$G = 1$ $V_{IN} \bullet G = V_S$		* * *			35 0.01 60		kHz V/μs μs
OUTPUT Voltage Output Swing from Rail <sup>(2)</sup> $T_A = -40^{\circ}C$ to $+85^{\circ}C$	Vo	$\begin{array}{l} R_L = 100 k\Omega, \ A_{OL} \geq 70 dB \\ R_L = 100 k\Omega, \ A_{OL} \geq 100 dB \\ R_L = 100 k\Omega, \ A_{OL} \geq 100 dB \\ R_L = 20 k\Omega, \ A_{OL} \geq 100 dB \end{array}$		* *			50 75 100	250 <b>250</b> 300	mV mV mV mV
$T_A = -40^{\circ}C$ to +85°C Short-Circuit Current Single Versions Dual Versions Capacitive Load Drive	I <sub>SC</sub> C <sub>LOAD</sub>	$R_{L} = 20k\Omega, A_{OL} \ge 100dB$ $R_{L} = 20k\Omega, A_{OL} \ge 100dB$		* *		See	-21/+4 -50/+4 Typical C	300	mV mA mA
POWER SUPPLYSpecified Voltage RangeOperating Voltage RangeQuiescent Current (per amplifier) $T_A = -40^{\circ}$ C to $+85^{\circ}$ C	V <sub>s</sub> I <sub>Q</sub>	$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $I_{O} = 0$ $I_{O} = 0$	*	*	*	±1.35	±15 ±27	±18 ±38 ±45	ν ν μΑ μΑ
TEMPERATURE RANGE Specified Range Operating Range Storage Range Thermal Resistance	$ heta_{JA}$		* *		* * *	-40 -55 -55		+85 +125 +125	⊃° ⊃°
8-Pin DIP SO-8 Surface Mount 14-Pin DIP SO-14 Surface Mount				* * * *			100 150 80 100		°C/W °C/W °C/W °C/W

 $\boldsymbol{\ast}$  Specifications the same as OPA251UA, PA.

NOTES: (1) The negative sign indicates input bias current flows out of the input terminals. (2) Output voltage swings are measured between the output and power supply rails.



#### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Supply Voltage, V+ to V	
Input Voltage <sup>(2)</sup>	
Output Short Circuit to Ground <sup>(3)</sup>	Continuous
Operating Temperature	–55°C to +125°C
Storage Temperature	–55°C to +125°C
Junction Temperature	150°C
Lead Temperature (soldering, 10s)	300°C

NOTES: (1) Stresses above these ratings may cause permanent damage. (2) Input terminals are diode-clamped to the power supply rails. Input signals that can swing more that 0.5V beyond the supply rails should be current-limited to 5mA or less. (3) One amplifier per package.



This integrated circuit can be damaged by ESD. Burr-Brown recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### PACKAGE/ORDERING INFORMATION

PRODUCT	SPECIFIED VOLTAGE			PACKAGE DRAWING NUMBER <sup>(1)</sup>	SPECIFICATION TEMPERATURE RANGE
OPA241 SERIES	-				•
Single OPA241PA OPA241UA	2.7V to 5V 2.7V to 5V	2.7V to 36V 2.7V to 36V	8-Pin DIP SO-8 Surface Mount	006 182	-40°C to +85°C -40°C to +85°C
<b>Dual</b> OPA2241PA OPA2241UA	2.7V to 5V 2.7V to 5V	2.7V to 36V 2.7V to 36V	8-Pin DIP SO-8 Surface Mount	006 182	-40°C to +85°C -40°C to +85°C
<b>Quad</b> OPA4241PA OPA4241UA	2.7V to 5V 2.7V to 5V	2.7V to 36V 2.7V to 36V	14-Pin DIP SO-14 Surface Mount	010 235	-40°C to +85°C -40°C to +85°C
OPA251 SERIES		•			•
<b>Single</b> OPA251PA OPA251UA	±15V ±15V	2.7V to 36V 2.7V to 36V	8-Pin DIP SO-8 Surface Mount	006 182	-40°C to +85°C -40°C to +85°C
Dual OPA2251PA OPA2251UA	±15V ±15V	2.7V to 36V 2.7V to 36V	8-Pin DIP SO-8 Surface Mount	006 182	-40°C to +85°C -40°C to +85°C
<b>Quad</b> OPA4251PA OPA4251UA	±15V ±15V	2.7V to 36V 2.7V to 36V	14-Pin DIP SO-14 Surface Mount	010 235	-40°C to +85°C -40°C to +85°C

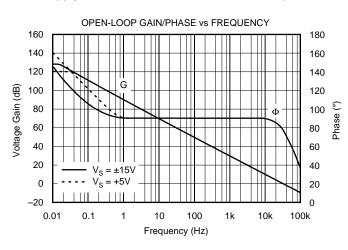
NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix C of Burr-Brown IC Data Book.

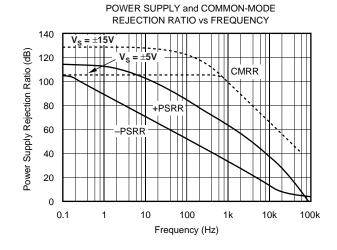


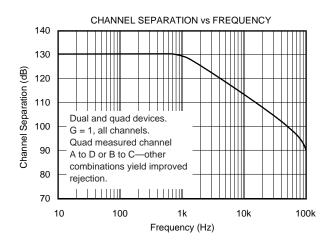
# **TYPICAL PERFORMANCE CURVES**

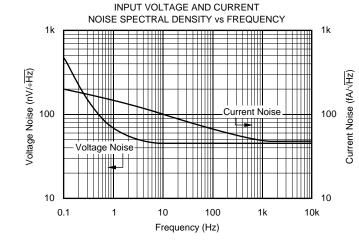
At  $T_A = +25^{\circ}C$ , and  $R_L = 100k\Omega$  connected to  $V_S/2$  (ground for  $V_S = \pm 15V$ ), unless otherwise noted.

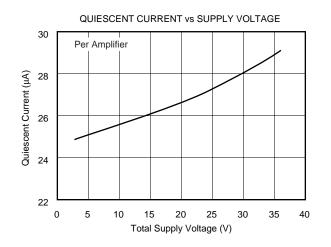
Curves apply to OPA241 and OPA251 unless specified.



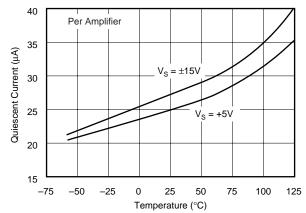








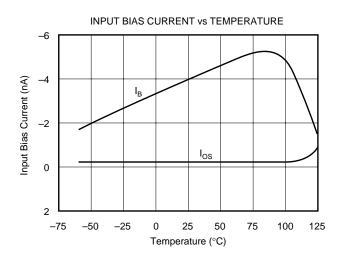
QUIESCENT CURRENT vs TEMPERATURE

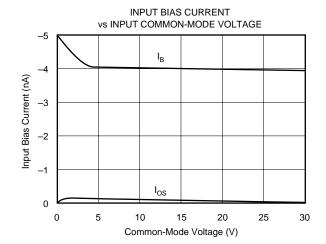




# **TYPICAL PERFORMANCE CURVES (CONT)**

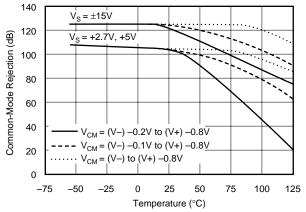
At  $T_A = +25^{\circ}$ C, and  $R_L = 100 k\Omega$  connected to  $V_S/2$  (ground for  $V_S = \pm 15$ V), unless otherwise noted. Curves apply to OPA241 and OPA251 unless specified.

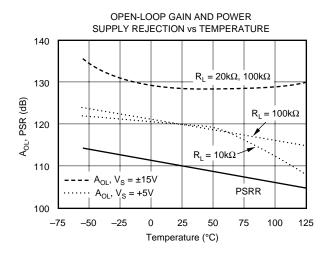


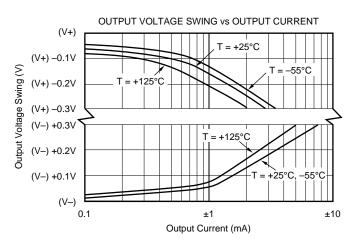


SHORT-CIRCUIT CURRENT vs TEMPERATURE 50 .... 45 40 Short-Circuit Current (mA) I<sub>sc</sub> 35 +5V ٧s 30 25  $V_s = +5V$ 20 Single Versions 15 ····· Dual, Quad Versions  $V_s = \pm 15V$ 10  $+I_{SC}$ ,  $V_{S} = +5V$ ,  $\pm 15V$  (all versions) 5 0 25 50 75 100 -75 -50 -25 0 125 Temperature (°C)





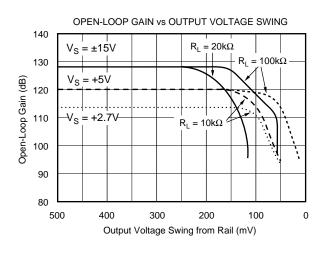


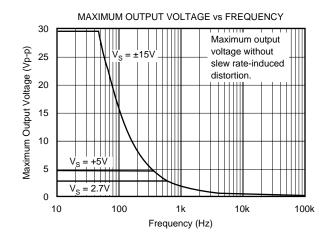




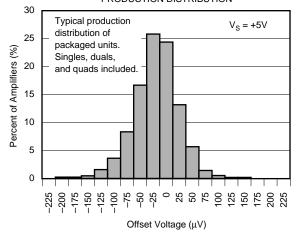
# **TYPICAL PERFORMANCE CURVES (CONT)**

At  $T_A = +25^{\circ}$ C, and  $R_L = 100 k\Omega$  connected to  $V_S/2$  (ground for  $V_S = \pm 15$ V), unless otherwise noted. Curves apply to OPA241 and OPA251 unless specified.



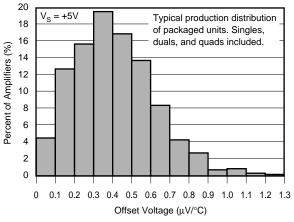


OPA241 SERIES OFFSET VOLTAGE PRODUCTION DISTRIBUTION

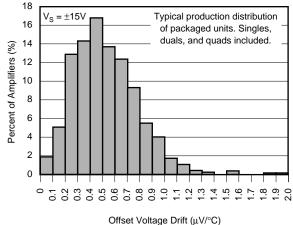


**OPA251 SERIES OFFSET VOLTAGE** PRODUCTION DISTRIBUTION 30  $V_{S} = \pm 15V$ Typical production distribution of 25 packaged units. Percent of Amplifiers (%) Singles, duals, 20 and quads included. 15 10 5 0 Offset Voltage (µV)

OPA241 SERIES OFFSET VOLTAGE DRIFT PRODUCTION DISTRIBUTION



OPA251 SERIES OFFSET VOLTAGE DRIFT PRODUCTION DISTRIBUTION



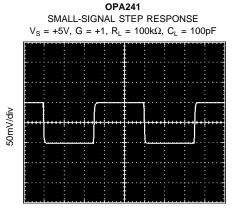
OPA241, 2241, 4241 OPA251, 2251, 4251



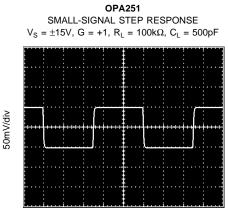
# **TYPICAL PERFORMANCE CURVES (CONT)**

At  $T_A = +25^{\circ}$ C, and  $R_L = 100$ k $\Omega$  connected to  $V_S/2$  (ground for  $V_S \pm 15$ V), unless otherwise noted. Curves apply to OPA241 and OPA251 unless specified.

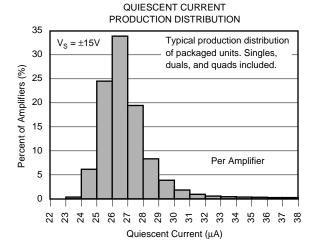
QUIESCENT CURRENT PRODUCT DISTRIBUTION 25  $V_{S} = +5V$ Typical production distribution of packaged units. 20 Percent of Amplifiers (%) Per Amplifier Singles, duals, and quads included. 15 10 5 0 Quiescent Current (µA)

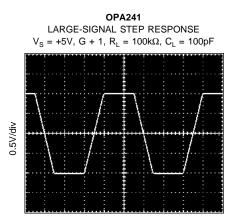


200µs/div

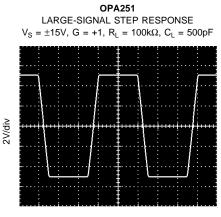








200µs/div



2ms/div



## **APPLICATIONS INFORMATION**

The OPA241 and OPA251 series are unity-gain stable and suitable for a wide range of general purpose applications. Power supply pins should be bypassed with  $0.01\mu F$  ceramic capacitors.

#### **OPERATING VOLTAGE**

The OPA241 series is laser-trimmed for low offset voltage and drift at low supply voltage ( $V_S = +5V$ ). The OPA251 series is trimmed for  $\pm 15V$  operation. Both products operate over the full voltage range (+2.7V to +36V or  $\pm 1.35V$  to  $\pm 18V$ ) with some compromises in offset voltage and drift performance. However, all other parameters have similar performance. Key parameters are guaranteed over the specified temperature range, -40°C to +85°C. Most behavior remains unchanged throughout the full operating voltage range. Parameters which vary significantly with operating voltage or temperature are shown in typical performance curves.

#### **OFFSET VOLTAGE TRIM**

As mentioned previously, offset voltage of the OPA241 series is laser-trimmed at  $\pm$ 5V. The OPA251 series is trimmed at  $\pm$ 15V. Because the initial offset is so low, user adjustment is usually not required. However, the OPA241 and OPA251 (single op amp versions) provide offset voltage trim connections on pins 1 and 5. Offset voltage can be adjusted by connecting a potentiometer as shown in Figure 1. This adjustment should be used only to null the offset of the op amp, not to adjust system offset or offset produced by the signal source. Nulling offset could degrade the offset drift behavior of the op amp. While it is not possible to predict the exact change in drift, the effect is usually small.

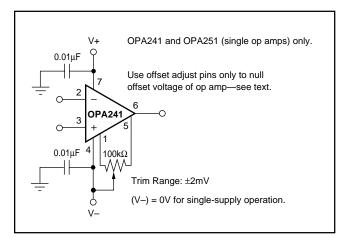


FIGURE 1. OPA241 and OPA251 Offset Voltage Trim Circuit.

#### CAPACITIVE LOAD AND STABILITY

The OPA241 series and OPA251 series can drive a wide range of capacitive loads. However, all op amps under certain conditions may be unstable. Op amp configuration, gain, and load value are just a few of the factors to consider when determining stability. Figures 2 and 3 show the regions where the OPA241 series and OPA251 series have the potential for instability. As shown, the unity gain configuration with low supplies is the most susceptible to the effects of capacitive load. With  $V_S =$ +5V, G = +1, and  $I_{OUT} = 0$ , operation remains stable with load capacitance up to approximately 200pF. Increasing supply voltage, output current, and/or gain significantly improves capacitive load drive. For example, increasing the supplies to ±15V and gain to 10 allows approximately 2700pF to be driven.

One method of improving capacitive load drive in the unity gain configuration is to insert a resistor inside the feedback loop as shown in Figure 4. This reduces ringing with large capacitive loads while maintaining dc accuracy. For example, with  $V_S = \pm 1.35V$  and  $R_S = 5k\Omega$ , the OPA241 series and OPA251 series perform well with capacitive loads in excess of 1000pF. Without the series resistor, capacitive load drive is typically 200pF for these conditions. However, this method will result in a slight reduction of output voltage swing.

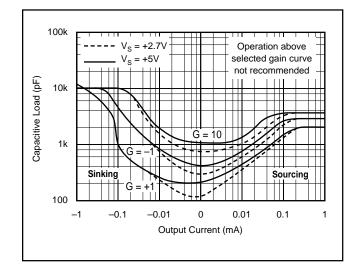


FIGURE 2. Stability—Capacitive Load versus Output Current for Low Supply Voltage.

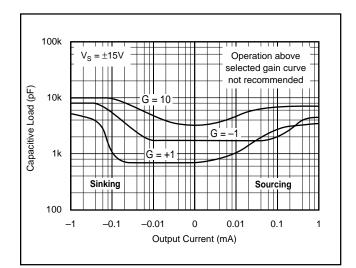


FIGURE 3. Stability—Capacitive Load versus Output Current for ±15V Supplies.



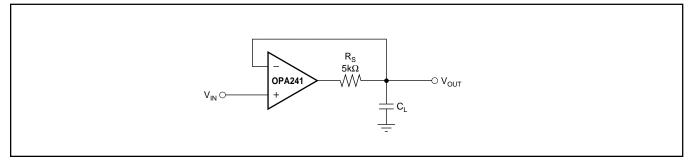


FIGURE 4. Series Resistor in Unity Gain Configuration Improves Capacitive Load Drive.

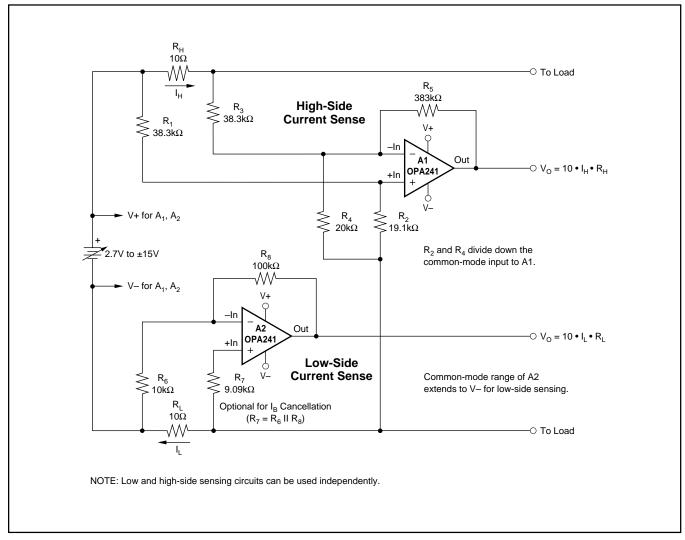


FIGURE 5. Low and High-Side Battery Current Sensing.





### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
OPA2241PA	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	OPA2241PA	Samples
OPA2241PAG4	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	OPA2241PA	Samples
OPA2241UA	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	OPA 2241UA	Samples
OPA2241UA/2K5	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	OPA 2241UA	Samples
OPA2241UAG4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	OPA 2241UA	Samples
OPA2251PA	ACTIVE	PDIP	Ρ	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	OPA2251PA	Samples
OPA2251PAG4	ACTIVE	PDIP	Р	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	OPA2251PA	Samples
OPA2251UA	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	OPA 2251UA	Samples
OPA2251UA/2K5	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	OPA 2251UA	Samples
OPA2251UAG4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	OPA 2251UA	Samples
OPA241PA	ACTIVE	PDIP	Ρ	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type		OPA241PA	Samples
OPA241UA	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	OPA 241UA	Samples
OPA241UA/2K5	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	OPA 241UA	Samples
OPA241UAG4	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	OPA 241UA	Samples
OPA251UA	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	OPA 251UA	Samples
OPA251UA/2K5	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 85	OPA 251UA	Samples
OPA4241PA	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	OPA4241PA	Samples
OPA4241UA	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU-DCC	Level-3-260C-168 HR	-40 to 85	OPA4241UA	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
OPA4241UA/2K5	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU-DCC	Level-3-260C-168 HR	-40 to 85	OPA4241UA	Samples
OPA4251UA	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU-DCC	Level-3-260C-168 HR	-40 to 85	OPA4251UA	Samples
OPA4251UA/2K5	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU-DCC	Level-3-260C-168 HR	-40 to 85	OPA4251UA	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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Texas

STRUMENTS

### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



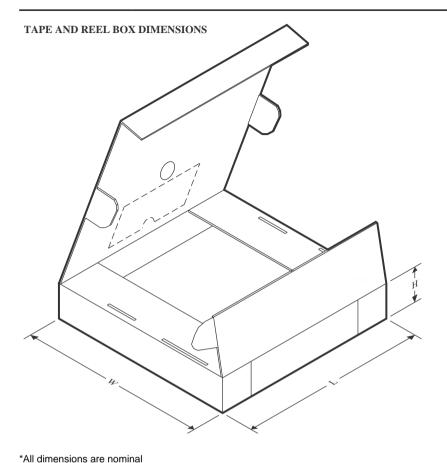
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
OPA2241UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA2251UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA241UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA251UA/2K5	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
OPA4241UA/2K5	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
OPA4251UA/2K5	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1



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## PACKAGE MATERIALS INFORMATION

9-Aug-2022



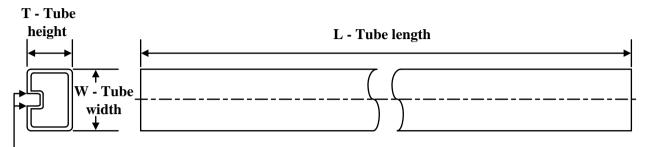
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA2241UA/2K5	SOIC	D	8	2500	356.0	356.0	35.0
OPA2251UA/2K5	SOIC	D	8	2500	356.0	356.0	35.0
OPA241UA/2K5	SOIC	D	8	2500	356.0	356.0	35.0
OPA251UA/2K5	SOIC	D	8	2500	356.0	356.0	35.0
OPA4241UA/2K5	SOIC	D	14	2500	356.0	356.0	35.0
OPA4251UA/2K5	SOIC	D	14	2500	356.0	356.0	35.0

### TEXAS INSTRUMENTS

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### TUBE



### - B - Alignment groove width

*All dimensions are nominal	
-----------------------------	--

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
OPA2241PA	Р	PDIP	8	50	506	13.97	11230	4.32
OPA2241PAG4	Р	PDIP	8	50	506	13.97	11230	4.32
OPA2241UA	D	SOIC	8	75	506.6	8	3940	4.32
OPA2241UAG4	D	SOIC	8	75	506.6	8	3940	4.32
OPA2251PA	Р	PDIP	8	50	506	13.97	11230	4.32
OPA2251PAG4	Р	PDIP	8	50	506	13.97	11230	4.32
OPA2251UA	D	SOIC	8	75	506.6	8	3940	4.32
OPA2251UAG4	D	SOIC	8	75	506.6	8	3940	4.32
OPA241PA	Р	PDIP	8	50	506	13.97	11230	4.32
OPA241UA	D	SOIC	8	75	506.6	8	3940	4.32
OPA241UAG4	D	SOIC	8	75	506.6	8	3940	4.32
OPA251UA	D	SOIC	8	75	506.6	8	3940	4.32
OPA4241PA	N	PDIP	14	25	506	13.97	11230	4.32
OPA4241UA	D	SOIC	14	50	506.6	8	3940	4.32
OPA4251UA	D	SOIC	14	50	506.6	8	3940	4.32

P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



## N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
   E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## **D0008A**



## **PACKAGE OUTLINE**

### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- This dimension does not include interlead flash.
   Reference JEDEC registration MS-012, variation AA.



## D0008A

# **EXAMPLE BOARD LAYOUT**

### SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## D0008A

# **EXAMPLE STENCIL DESIGN**

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



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